



Specification for a Sinewave Output Thru-Hole OCXO MtronPTI P/N: XO5085-109R

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Nominal Frequency	Fo		100.000000		MHz	
		F	Frequency Stab	ilities		
vs. Temperature	∆F⊤/F	-100		+100	ppb	Over the Operating Temperature Range
vs. Supply voltage variation		-30		+30	ppb	+/-250mV change in supply voltage
Daily Aging		-5		+5	ppb	
1 Year Aging		-0.5		+0.5	ppm	After 30-days Power On
10-Years Aging		-2.0		+2.0	ppm	
			RF Output			
Output Type			Sinewave			
Output Level			+13		dBm	
Output Load			50		Ω	±10%
		F	requency Adjus	stment		
Adjustment Method			External V	Voltage		
Adjustment Voltage	VTUNE	0		+10	VDC	
Adjustment Range		±0.5			ppm	Over all conditions
Adjustment Slope			Posit			
		Α	dditional Parar	neters		
				-97	dBc/Hz	10Hz Offset
				-130	dBc/Hz	100Hz Offset
Phase Noise				-160	dBc/Hz	1kHz Offset
(Under Static				-172	dBc/Hz	10kHz Offset
Conditions)				-172	dBc/Hz	100kHz Offset
				-172	dBc/Hz	1MHz Offset
				-172	dBc/Hz	10MHz Offset
G-sensitivity			1.5		ppb/g	
Harmonics				-25	dBc	
Spurious				-80	dBc	
Warm-up Time				5	minutes	To within ±0.1ppm of the frequency after 1-hour of operation @ 25°C
`		perature, Su	pply Voltage &	Power Con	sumption	
Operating Temperature	OTR	-25		+80	0°	Full Specification Compliance
Storage Temperature	STR	-55		+85	°C	
Operating Voltage	Vcc	+11.4	+12.0	+12.6	VDC	
Power Consumption				1.5	Watts	Steady state @ 25°C, In Still Air
				3.6	Watts	@ Warm-up



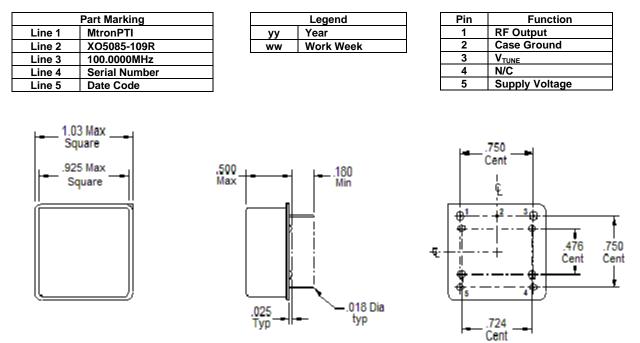


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Environmental Conditions:

Seal	Hermetic
RoHS	Full RoHS Compliance

Mechanical, Marking and Layout Information:



Data Sheet Revision Table:

Date	Rev.	Orig.	Details of Revision
05-08-19	В	DPD	Revised datasheet
03-22-19	A	BRR	Original release